

PLASTIC SILICON RECTIFIERS

REVERSE VOLTAGE - **50 to 1000** Volts
FORWARD CURRENT - **1.0** Ampere

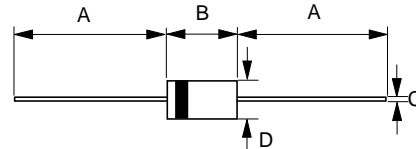
FEATURES

- Low cost
- Diffused junction
- Low forward voltage drop
- Low reverse leakage current
- High current capability
- The plastic material carries UL recognition 94V-0

MECHANICAL DATA

- Case : JEDEC A-405 molded plastic
- Polarity : Color band denotes cathode
- Weight : 0.008 ounces, 0.22 grams
- Mounting position : Any

A-405



A-405		
Dim.	Min.	Max.
A	25.4	-
B	4.10	5.20
C	0.53 \varnothing	0.64 \varnothing
D	2.00 \varnothing	2.70 \varnothing
All Dimensions in millimeter		

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	1N4001L	1N4002L	1N4003L	1N4004L	1N4005L	1N4006L	1N4007L	UNIT
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @T _A =75°C	I(AV)	1.0							A
Peak Forward Surge Current 8.3ms single half sine-wave super imposed on rated load (JEDEC Method)	I _{FSM}	30							A
Maximum forward Voltage at 1.0A DC	V _F	1.0							V
Maximum DC Reverse Current at Rated DC Blocking Voltage @T _J =25°C @T _J =100°C	I _R	5.0 50							uA
Typical Junction Capacitance (Note 1)	C _J	15							pF
Typical Thermal Resistance (Note 2)	R _{θJA}	50							°C/W
Operating Temperature Range	T _J	-55 to +125							°C
Storage Temperature Range	T _{STG}	-55 to +150							°C

NOTES : 1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
2.Thermal Resistance Junction to Ambient.

FIG.1 - FORWARD CURRENT DERATING CURVE

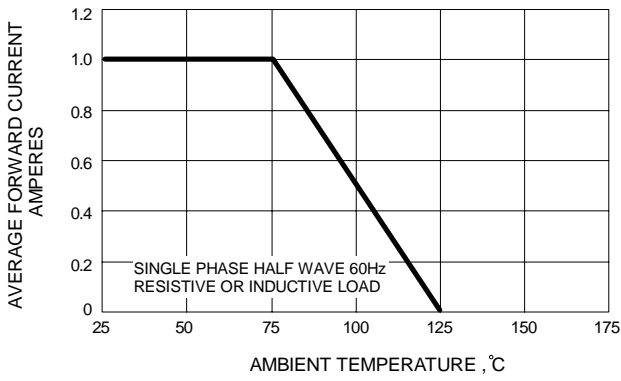


FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

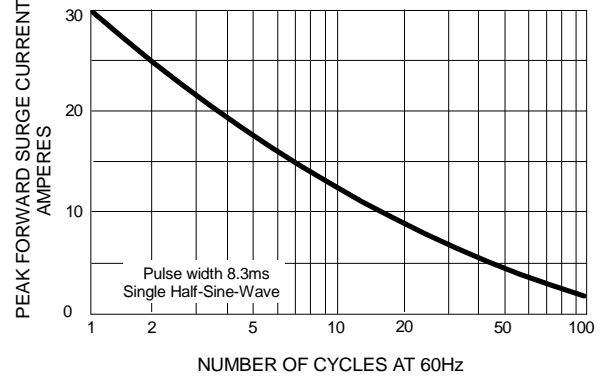


FIG.3 - TYPICAL JUNCTION CAPACITANCE

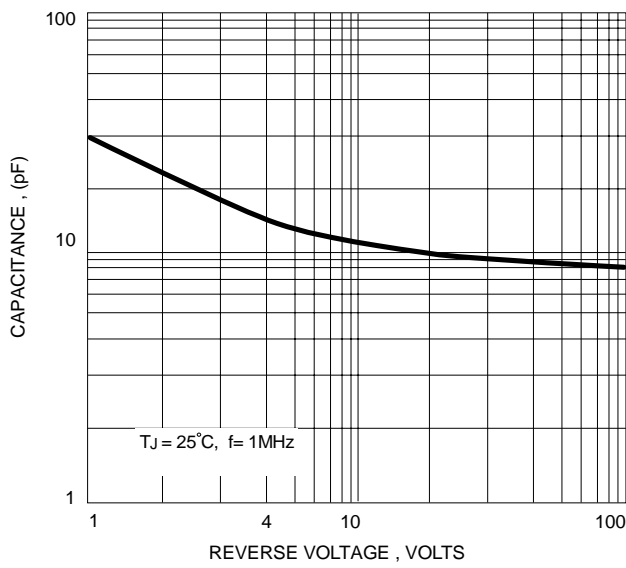


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

